

### Discrete POWER & Signal **Technologies**

# 2N3416 2N3417



## **NPN General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100A for characteristics.

### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |
|-----------------------------------|--|-------------|-------|
| $V_{CEO}$                         | Collector-Emitter Voltage                        | 50          | V     |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 50          | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 5.0         | V     |
| lc                                | Collector Current - Continuous                   | 500         | mA    |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### **Thermal Characteristics** TA = 25°C unless otherwise noted

| Symbol          | Characteristic                          | Max             | Units |  |
|-----------------|---|-----------------|-------|--|
|                 |   | 2N3416 / 2N3417 |       |  |
| P <sub>D</sub>  | Total Device Dissipation                | 625             | mW    |  |
|                 | Derate above 25°C                       | 5.0             | mW/°C |  |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case    | 83.3            | °C/W  |  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 200             | °C/W  |  |

# **NPN General Purpose Amplifier**

100

(continued)

nΑ

| Electrical Characteristics TA = 25°C unless otherwise noted |   |  |     |           |          |  |
|---|---|--|-----|-----------|----------|--|
| Symbol  | Parameter                               | Test Conditions  |     | Max       | Units    |  |
| OFF CHA   | RACTERISTICS                            |  |     |           |          |  |
| $V_{(BR)CEO}$   | Collector-Emitter Breakdown<br>Voltage* | $I_C = 10 \text{ mA}, I_B = 0$   | 50  |           | V        |  |
| V <sub>(BR)CBO</sub>  | Collector-Base Breakdown Voltage        | $I_C = 10 \mu A, I_E = 0$  | 50  |           | V        |  |
| V <sub>(BR)EBO</sub>  | Emitter-Base Breakdown Voltage          | $I_E = 10 \mu A, I_C = 0$  | 5.0 |           | V        |  |
| I <sub>CBO</sub>  | Collector-Cutoff Current                | V <sub>CB</sub> = 25 V, I <sub>E</sub> = 0<br>V <sub>CB</sub> = 18 V, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C |     | 100<br>15 | nA<br>μA |  |
|   | E 1:: 0 : # 0                           | 1/ -01/1   |     | 400       | ,,,,,    |  |

### ON CHARACTERISTICS\*

 $I_{EBO}$ 

| h <sub>FE</sub>      | DC Current Gain                      | $V_{CE} = 4.5 \text{ V}, I_{C} = 2.0 \text{ mA}$ |     |     |   |
|----------------------|--------------------------------------|--|-----|-----|---|
|                      |                                      | 2N3416   | 75  | 225 |   |
|                      |                                      | 2N3417   | 180 | 540 |   |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | $I_C = 50 \text{ mA}, I_B = 3.0 \text{ mA}$      |     | 0.3 | V |
| V <sub>BE(sat)</sub> | Base-Emitter Saturation Voltage      | $I_C = 50 \text{ mA}, I_B = 3.0 \text{ mA}$      | 0.6 | 1.3 | V |

 $V_{EB} = 5.0 \text{ V}, I_{C} = 0$ 

### SMALL SIGNAL CHARACTERISTICS

**Emitter-Cutoff Current** 

| h <sub>fe</sub> | Small-Signal Current Gain | $I_C = 2.0 \text{ mA}, V_{CE} =$ |        |     |  |
|-----------------|---------------------------|----------------------------------|--------|-----|--|
|                 |                           | f = 1.0 kHz                      | 2N3416 | 75  |  |
|                 |                           |                                  | 2N3417 | 180 |  |

<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%